



**Nobuyoshi Koshida**

**Nobuyoshi Koshida** received the PhD degree in 1973 from Tohoku University, Sendai, Japan, in the field of electronic engineering. After working as a researcher in the Central Laboratories of Nissan Motor Co. Ltd., he moved to Tokyo University of Agriculture and Technology as an associate professor in 1981. He has been working there as a professor of electronic device engineering since 1988, and as a professor of strategic research initiative for future nanoscience and technology in the Graduate School of Engineering since 2002.

Related professional careers are a visiting scientist in the Department of Electrical Engineering and Computer Science, Massachusetts Institute of Technology, USA, in 1992-1993; in Cavendish Laboratory, Cambridge University, UK, in 1993; and an invited visiting professor at J.-Fourier University Grenoble, France, in 1996.

His research interests include the implementation of optoelectronic, electronic, acoustic, and biological nanosilicon devices toward functional integration. He has presented over 320 publications, including journal papers, conference papers, book chapters, and review articles (<http://www.tuat.ac.jp/~koslab/>), and 70 patents. He was awarded a Fellowship of the Electrochemical Society and the Japan Applied Physics Society in 2006 and 2007, respectively.